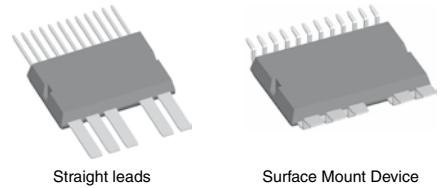
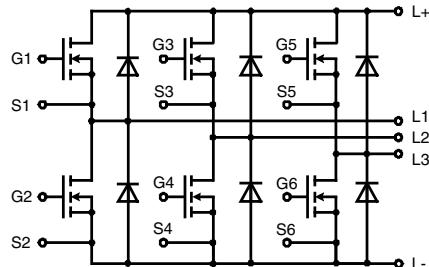


## Three phase full Bridge

with Trench MOSFETs  
in DCB isolated high current package

**V<sub>DSS</sub>** = 85 V  
**I<sub>D25</sub>** = 103 A  
**R<sub>DSon typ.</sub>** = 5.5 mΩ



### MOSFETs

Symbol	Conditions	Maximum Ratings		
<b>V<sub>DSS</sub></b>	T <sub>J</sub> = 25°C to 150°C	85		V
<b>V<sub>GS</sub></b>		± 20		V
<b>I<sub>D25</sub></b>	T <sub>C</sub> = 25°C	103		A
<b>I<sub>D90</sub></b>	T <sub>C</sub> = 90°C	77		A
<b>I<sub>D110</sub></b>	T <sub>C</sub> = 110°C	68		A
<b>I<sub>F25</sub></b>	T <sub>C</sub> = 25°C (diode)	tbd		A
<b>I<sub>F90</sub></b>	T <sub>C</sub> = 90°C (diode)	tbd		A
<b>I<sub>F110</sub></b>	T <sub>C</sub> = 110°C (diode)	tbd		A

### Symbol Conditions

Symbol	Conditions	Characteristic Values		
		(T <sub>J</sub> = 25°C, unless otherwise specified)	min.	typ.
<b>R<sub>DSon</sub></b> <sup>1)</sup>	on chip level at V <sub>GS</sub> = 10 V; I <sub>D</sub> = 75 A	T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C		5.5 12.7
<b>V<sub>GS(th)</sub></b>	V <sub>DS</sub> = 20 V; I <sub>D</sub> = 250 μA		2.0	4.0
<b>I<sub>DSS</sub></b>	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0 V	T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C		5 100
<b>I<sub>GSS</sub></b>	V <sub>GS</sub> = ± 20 V; V <sub>DS</sub> = 0 V			0.2
<b>Q<sub>g</sub></b> <b>Q<sub>gs</sub></b> <b>Q<sub>gd</sub></b>	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 42 V; I <sub>D</sub> = 75 A		114 30 35	nC nC nC
<b>t<sub>d(on)</sub></b> <b>t<sub>r</sub></b> <b>t<sub>d(off)</sub></b> <b>t<sub>f</sub></b>	inductive load V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 42 V I <sub>D</sub> = 75 A; R <sub>G</sub> = 39 Ω; T <sub>J</sub> = 125°C		tbd tbd tbd tbd	ns ns ns ns
<b>E<sub>on</sub></b> <b>E<sub>off</sub></b> <b>E<sub>recoff</sub></b>			tbd tbd tbd	mJ mJ mJ
<b>R<sub>thJC</sub></b> <b>R<sub>thJH</sub></b>	with heat transfer paste (IXYS test setup)		1.3	1.0 1.6
<sup>1)</sup> V <sub>DS</sub> = I <sub>D</sub> · (R <sub>DS(on)</sub> + R <sub>Pin to Chip</sub> )				

### Applications

- AC drives
  - in automobiles
  - electric power steering
  - starter generator
- in industrial vehicles
  - propulsion drives
  - fork lift drives
- in battery supplied equipment

### Features

- MOSFETs in trench technology:
  - low RDson
  - optimized intrinsic reverse diode
- package:
  - high level of integration
  - high current capability 300 A max.
  - aux. terminals for MOSFET control
  - terminals for soldering or welding connections
  - isolated DCB ceramic base plate with optimized heat transfer
- Space and weight savings

### Package options

- 2 lead forms available
  - straight leads (SL)
  - SMD lead version (SMD)

**Source-Drain Diode**

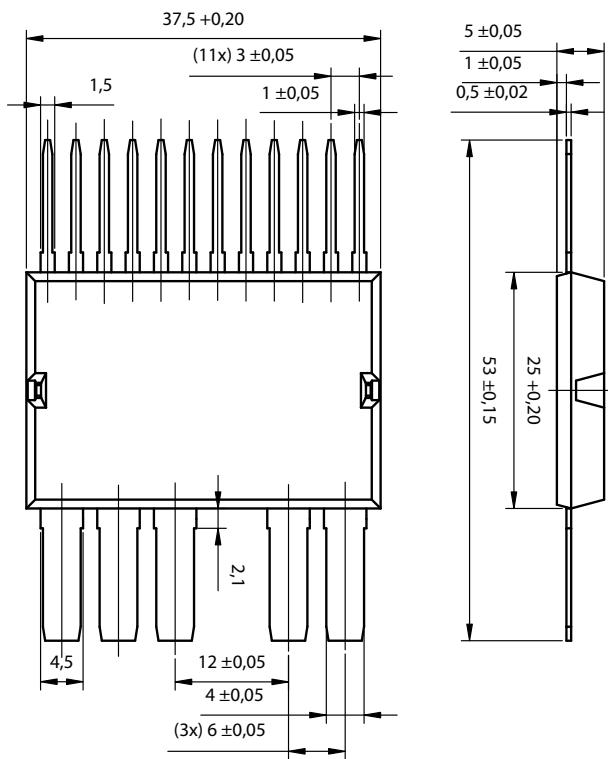
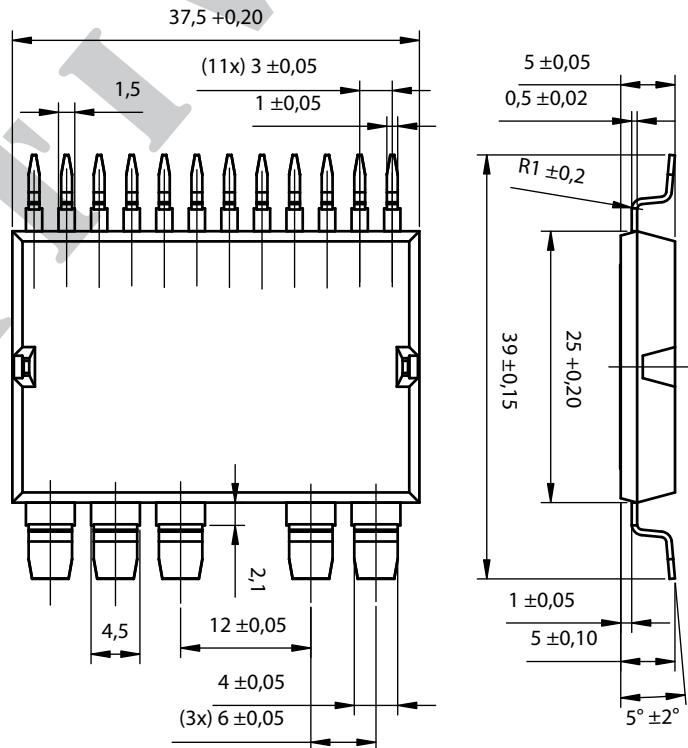
Symbol	Conditions	Characteristic Values		
		(T <sub>J</sub> = 25°C, unless otherwise specified)		
		min.	typ.	max.
V <sub>SD</sub>	(diode) I <sub>F</sub> = 100 A; V <sub>GS</sub> = 0 V	0.9	1.2	V
t <sub>rr</sub> Q <sub>RM</sub> I <sub>RM</sub>	I <sub>F</sub> = 100 A; -di <sub>F</sub> /dt = 800 A/μs; V <sub>R</sub> = 24 V T <sub>VJ</sub> = 125°C	tbd tbd tbd		ns μC A

**Component**

Symbol	Conditions	Maximum Ratings		
I <sub>RMS</sub>	per pin in main current paths (P+, N-, L1, L2, L3) may be additionally limited by external connections	300	A	
T <sub>J</sub>		-55...+175	°C	
T <sub>stg</sub>		-55...+125	°C	
V <sub>ISOL</sub>	I <sub>ISOL</sub> ≤ 1 mA, 50/60 Hz, f = 1 minute	1000	V~	
F <sub>c</sub>	mounting force with clip	50 - 250	N	

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R <sub>pin to chip</sub> <sup>1)</sup>	L+ to L1/L2/L3 or L- to L1/L2/L3		1.0	mΩ
C <sub>P</sub>	coupling capacity between shorted pins and mounting tab in the case		160	pF
Weight			25	g

<sup>1)</sup> V<sub>DS</sub> = I<sub>D</sub>·(R<sub>DS(on)</sub> + R<sub>Pin to Chip</sub>)

**Straight Leads****GWM 100-085X1-SL****Surface Mount Device****GWM 100-085X1-SMD**

Leads	Ordering	Part Name & Packing Unit Marking	Part Marking	Delivering Mode	Base Qty.	Ordering Code
Straight	Standard	GWM 100-0085X1 - SL	GWM 100-0085X1	Blister	28	tbd
SMD	Standard	GWM 100-0085X1 - SMD	GWM 100-0085X1	Blister	28	tbd